

# New Jersey Semi-Conductor Products, Inc.

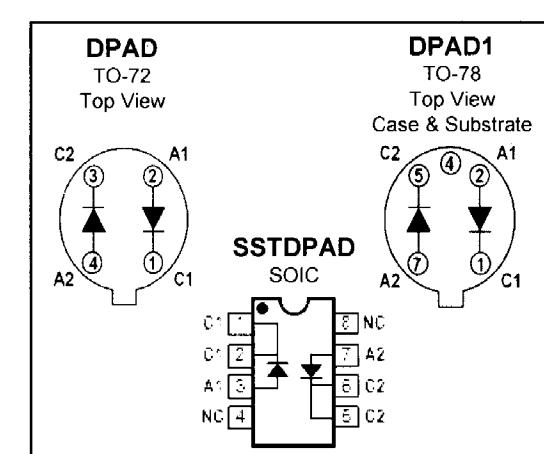
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## DPAD SERIES

### MONOLITHIC DUAL PICO AMPERE DIODES

FEATURES	
Direct Replacement For SILICONIX DPAD SERIES	
HIGH ON ISOLATION	20fA
EXCELLENT CAPACITANCE MATCHING	$\Delta C_R \leq 0.2\text{pF}$
ABSOLUTE MAXIMUM RATINGS <sup>1</sup>	
@ 25°C (unless otherwise stated)	
Maximum Temperatures	
Storage Temperature	-55°C to +150°C
Operating Junction Temperature	-55°C to +150°C
Maximum Power Dissipation	
Continuous Power Dissipation (DPAD) <sup>3</sup>	500mW
Maximum Currents	
Forward Current (DPAD)	50mA



\* Case and Pin 4 must be floating on all TO-78 case devices

#### COMMON ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise stated)

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNITS	CONDITIONS
$BV_R$	Reverse Breakdown Voltage	DPAD1	-45		V	$I_R = -1\mu\text{A}$
		DPAD2,5,10,20,50,100	-45			
		SSTDPAD5,50,100	-30			
$V_F$	Forward Voltage		0.8	1.5		$I_F = 1\text{mA}$
$ C_{R1}-C_{R2} $	Differential Capacitance ( $\Delta C_R$ )	DPAD1		0.2	pF	$V_{R1} = V_{R2} = -5\text{V}, f=1\text{MHz}$
		ALL OTHERS		0.5		
$C_{rss}$	Total Reverse Capacitance	DPAD1		0.8		$V_R = -5\text{V}, f=1\text{MHz}$
		DPAD2,5,10,20,50,100		2.0		
		SSTDPAD5,50,100		4.0		

#### SPECIFIC ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise stated)

SYMBOL	CHARACTERISTIC	DPAD <sup>2</sup>	SSTDPAD <sup>2</sup>	UNITS	CONDITIONS
$I_R$	Maximum Reverse Leakage Current <sup>2</sup>	(SST)DPAD1	-1	pA	$V_R = -20\text{V}$
		(SST)DPAD2	-2		
		(SST)DPAD5	-5		
		(SST)DPAD10	-10		
		(SST)DPAD20	-20		
		(SST)DPAD50	-50		
		(SST)DPAD100	-100		

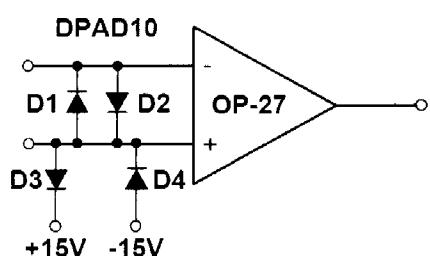
**Figure 1. Operational Amplifier Protection**

Input Differential Voltage limited to 0.8V (typ) by DPADs D<sub>1</sub> and D<sub>2</sub>. Common Mode Input voltage limited by DPADs D<sub>3</sub> and D<sub>4</sub> to  $\pm 15\text{V}$ .

**Figure 2. Sample and Hold Circuit**

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Typical Sample and Hold circuit with clipping. DPAD diodes reduce offset voltages fed capacitively from the JFET switch gate.

**FIGURE 1**



**FIGURE 2**

